

DS26LV32AT 3V Enhanced CMOS Quad Differential Line Receiver

Check for Samples: DS26LV32AT

FEATURES

- Low Power CMOS Design (30 mW typical)
- Interoperable with Existing 5V RS-422 Networks
- Industrial and Military Temperature Range
- Conforms to TIA/EIA-422-B (RS-422) and ITU-T V.11 Recommendation
- 3.3V Operation
- ±7V Common Mode Range @ V_{ID} = 3V
- ±10V Common Mode Range @ V_{ID} = 0.2V
- Receiver OPEN Input Failsafe Feature
- Guaranteed AC Parameter:
 - Maximum Receiver Skew: 4 ns
 - Maximum Transition Time: 10 ns
- Pin Compatible with DS26C32AT
- 32 MHz Toggle Frequency
- > 6.5k ESD Tolerance (HBM)

- Available in SOIC and CLGA Packaging
- Standard Microcircuit Drawing (SMD) 5962-98585

DESCRIPTION

The DS26LV32A is a high speed quad differential CMOS receiver that meets the requirements of both TIA/EIA-422-B and ITU-T V.11. The CMOS DS26LV32AT features typical low static $I_{\rm CC}$ of 9 mA which makes it ideal for battery powered and power conscious applications. The TRI-STATE enables, EN and EN*, allow the device to be active High or active Low. The enables are common to all four receivers.

The receiver output (RO) is guaranteed to be High when the inputs are left open. The receiver can detect signals as low as ±200 mV over the common mode range of ±10V. The receiver outputs (RO) are compatible with TTL and LVCMOS levels.

Connection Diagram

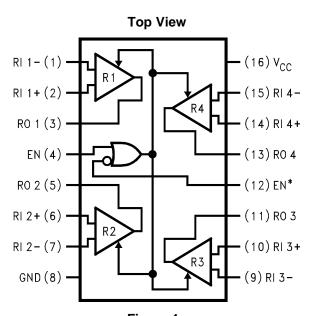


Figure 1.
SOIC Package
See Package Numbers D0016A or NAD0016A

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Truth Table⁽¹⁾

Enabl	es	Inputs	Output
EN	EN*	RI+-RI-	RO
L	Н	X	Z
All oth		V _{ID} ≥ +0.2V	Н
combinati enable ir		V _{ID} ≤ -0.2V	L
Chable II	ipato	Open ⁽²⁾	Н

L = Logic Low

H = Logic High X = Irrelevant

Z = TRI-STATE

Open, not terminated



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

Absolute Maximum Ratings (1)(2)

-0.5V to +7V		
-0.5V to V _{CC} +0.5V		
±14V		
±14V		
-0.5V to V _{CC} +0.5V		
±25 mA Maximum		
1190 mW		
1087 mV		
−65°C to +150°C		
+260°C		
≥ 6.5 kV		
≥ 2 kV		

[&]quot;Absolute Maximum ratings" are those values beyond which the safety of the device cannot be guaranteed. They are not meant to imply that the devices should be operated at these limits. The Electrical Characteristics specifies conditions of device operation.

Recommended Operating Conditions

· · · · · · · · · · · · · · · · · · ·					
	Mi	n	Тур	Max	Units
Supply Voltage (V _{CC})	3.	0	3.3	3.6	V
Operating Free Air Temperature Range (T _A)	•		·	•	
DS26LV32AT	-4	0	+25	+85	°C
DS26LV32AW	-5	5	+25	+125	°C

Product Folder Links: DS26LV32AT

If Military/Aerospace specified devices are required, please contact the TI Sales Office/Distributors for availability and specifications.



Electrical Characteristics (1) (2)

Over Supply Voltage and Operating Temperature ranges, unless otherwise specified.

Parameter		Test Co	nditions	Pin	Min	Тур	Max	Units
V _{TH}	Differential Input Threshold	rential Input Threshold $V_{OUT} = V_{OH} \text{ or } V_{OL}$ $V_{CM} = -7V \text{ to } + T_{A} = -40^{\circ}\text{C to } +85^{\circ}\text{C}$				±17.5	+200	mV
			$V_{CM} = -0.5V$ to +5.5V, $T_A = -55^{\circ}C$ to +125°C ⁽³⁾	RI+, RI-	-200		+200	mV
V_{HY}	Hysteresis	V _{CM} = 1.5V	1			35		mV
V _{IH}	Minimum High Level Input Voltage			EN,	2.0			V
V _{IL}	Maximum Low Level Input Voltage			EN*			0.8	V
R _{IN}	Input Resistance	$V_{IN} = -7V$, $+7V$, $T_A = (Other Input = GND)$	-40°C to +85°C		5.0	8.5		kΩ
		$V_{IN} = -0.5V, +5.5V, T$ (Other Input = GND)		5.0			kΩ	
I _{IN}	Input Current	V _{IN} = +10V	$T_A = -40^{\circ}C$ to		0	1.1	1.8	mA
	(Other Input = 0V,	$V_{IN} = +3V$	+85°C	RI+,	0	0.27		mA
	Power On, or	$V_{IN} = 0.5V$		RI-		-0.02		mA
	V _{CC} = 0V)	V _{IN} = −3V			0	-0.43		mA
		V _{IN} = −10V			0	-1.26	-2.2	mA
		V _{IN} = −0.5V	$T_A = -55^{\circ}C$ to		0		-1.8	mA
		$V_{IN} = 5.5V$	+125°C ⁽³⁾		0		1.8	mA
I _{EN}	Input Current	$V_{IN} = 0V \text{ to } V_{CC}$		EN, EN*			±1	μΑ
V_{OH}	High Level Output Voltage	$I_{OH} = -6 \text{ mA}, V_{ID} = +6 \text{ mA}$	1V		2.4	3		V
		$I_{OH} = -6 \text{ mA}, V_{ID} = O$	PEN		2.4	3		V
V_{OH}	High Level Output Voltage	$I_{OH} = -100 \mu A, V_{ID} =$	+1V			V _{CC} -0.1		V
		$I_{OH} = -100 \mu A, V_{ID} =$: OPEN	RO		VCC 0.1		V
V_{OL}	Low Level Output Voltage	$I_{OL} = +6 \text{ mA}, V_{ID} = -2$	IV	INO		0.13	0.5	V
I_{OZ}	Output TRI-STATE Leakage Current	$V_{OUT} = V_{CC}$ or GND EN = V_{IL} , EN* = V_{IH}					±50	μΑ
I _{sc}	Output Short Circuit Current	$V_{O} = 0V, V_{ID} \ge 200 \text{ n} $	nV ⁽⁴⁾		-10	-35	-70	mA
I _{CC}	Power Supply Current	No Load, All RI+, R1- = OPEN, EN,	T _A = -40°C to +85°C	V _{CC}		9	15	mA
		EN* = V_{CC} or GND $T_A = -55^{\circ}C \text{ to}$ +125°C					20	mA

⁽¹⁾ Current into device pins is defined as positive. Current out of device pins is defined as negative. All voltages are referenced to ground except $V_{\rm ID}$. All typicals are given for: $V_{\rm CC}$ = +3.3V, $T_{\rm A}$ = +25°C. This parameter does not meet the TIA/EIA-422-B specification.

⁽⁴⁾ Short one output at a time to ground. Do not exceed package.



Switching Characteristics - Industrial (1) (2)

Over Supply Voltage and -40°C to +85°C Operating Temperature range, unless otherwise specified.

Parameter		Test Conditions	Min	Тур	Max	Units
t _{PHL}	Propagation Delay High to Low	C _L = 15 pF, V _{CM} = 1.5V (Figure 2 and Figure 3)	6	17.5	35	ns
t _{PLH}	Propagation Delay Low to High		6	17.8	35	ns
t _r	Rise Time (20% to 80%)			4.1	10	ns
t _f	Fall Time (80% to 20%)			3.3	10	ns
t _{PHZ}	Disable Time	C _L = 50 pF, V _{CM} = 1.5V (Figure 4 and Figure 5)			40	ns
t _{PLZ}	Disable Time				40	ns
t _{PZH}	Enable Time				40	ns
t _{PZL}	Enable Time				40	ns
t _{SK1}	Skew, t _{PHL} - t _{PLH} (3)	C _L = 15 pF, V _{CM} = 1.5V		0.3	4	ns
t _{SK2}	Skew, Pin to Pin (4)			0.6	4	ns
t _{SK3}	Skew, Part to Part (2)			7	17	ns
f _{MAX}	Maximum Operating Frequency	C _L = 15 pF, V _{CM} = 1.5V	32			MHz

- (1) All typicals are given for: $V_{CC} = +3.3V$, $T_A = +25$ °C.
- (2) t_{SK3} is the difference in propagation delay times between any channels of any devices. This specification (maximum limit) applies to devices within V_{CC} ±0.1V of one another, and a Delta T_A = ±5°C (between devices) within the operating temperature range. This parameter is guaranteed by design and characterization.
- (3) t_{SK1} is the $|t_{PHL} t_{PLH}|$ of a channel.
- (4) t_{SK2} is the maximum skew between any two channels within a device, either edge.
- (5) All channels switching, Output Duty Cycle criteria is 40%/60% measured at 50%. Input = 1V to 2V, 50% Duty Cycle, t_f/t_f ≤ 5 ns. This parameter is guaranteed by design and characterization.

Switching Characteristics - Military

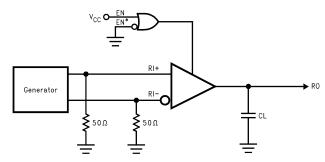
Over Supply Voltage and -55°C to +125°C Operating Temperature range, unless otherwise specified.

	Parameter	Parameter Test Conditions					
t _{PHL}	Propagation Delay High to Low	C _L = 50 pF, V _{CM} = 1.5V (Figure 2 and Figure 3)	6	45	ns		
t _{PLH}	Propagation Delay Low to High		6	45	ns		
t _{PHZ}	Disable Time	C _L = 50 pF, V _{CM} = 1.5V (Figure 4 and Figure 5)		50	ns		
t_{PLZ}	Disable Time			50	ns		
t _{PZH}	Enable Time			50	ns		
t _{PZL}	Enable Time			50	ns		
t _{SK1}	Skew, t _{PHL} - t _{PLH} (1)	$C_L = 50 \text{ pF}, V_{CM} = 1.5 \text{V}$		6	ns		
t _{SK2}	Skew, Pin to Pin (2)			6	ns		

- (1) t_{SK1} is the $|t_{PHL} t_{PLH}|$ of a channel.
- (2) t_{SK2} is the maximum skew between any two channels within a device, either edge.

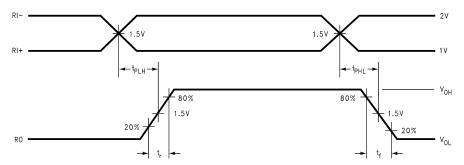


PARAMETER MEASUREMENT INFORMATION



- A. Generator waveform for all tests unless otherwise specified: f = 1 MHz, Duty Cycle = 50%, $Z_O = 50\Omega$, $t_r \le 10$ ns, $t_f \le 10$ ns.
- B. C_L includes probe and jig capacitance.

Figure 2. Receiver Propagation Delay and Transition Time Test Circuit



- A. Generator waveform for all tests unless otherwise specified: f = 1 MHz, Duty Cycle = 50%, $Z_O = 50\Omega$, $t_r \le 10$ ns, $t_f \le 10$ ns.
- B. C_L includes probe and jig capacitance.
- C. For military grade product, $t_r \le 6$ ns and $t_f \le 6$ ns.
- D. For military grade product the measure point is 1/2 V_{CC} for t_{PLH} , t_{PHL} , t_{PZL} , and t_{PZH} .

Figure 3. Receiver Propagation Delay and Transition Time Waveform

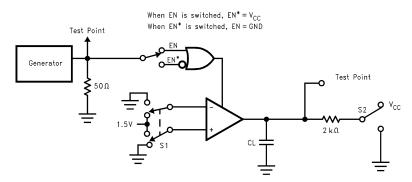
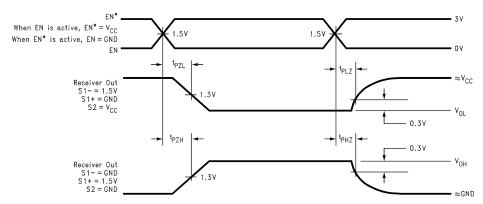


Figure 4. Receiver TRI-STATE Test Circuit

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- A. Generator waveform for all tests unless otherwise specified: f = 1 MHz, Duty Cycle = 50%, Z_O = 50Ω, t_f ≤ 10 ns, t_f ≤ 10 ns.
- B. C_L includes probe and jig capacitance.
- C. For military grade product, $t_r \le 6$ ns and $t_f \le 6$ ns.
- D. For military grade product the measure point is 1/2 V_{CC} for t_{PLH} , t_{PHL} , t_{PZL} , and t_{PZH} .

Figure 5. Receiver TRI-STATE Output Enable and Disable Waveforms



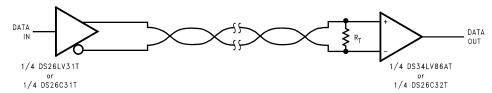
TYPICAL APPLICATION INFORMATION

General application guidelines and hints for differential drivers and receivers may be found in the following application notes:

- AN-214
- AN-457
- AN-805
- AN-847
- AN-903
- AN-912
- AN-916

Power Decoupling Recommendations:

Bypass caps must be used on power pins. High frequency ceramic (surface mount is recommended) 0.1 μ F in parallel with 0.01 μ F at the power supply pin. A 10 μ F or greater solid tantalum or electrolytic should be connected at the power entry point on the printed circuit board.



R_T is optional although highly recommended to reduce reflection

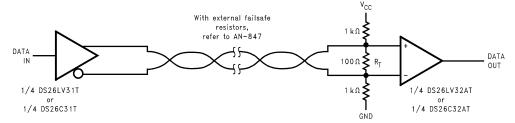


Figure 6. Typical Receiver Connections

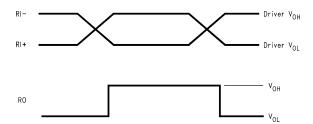


Figure 7. Typical Receiver Output Waveforms



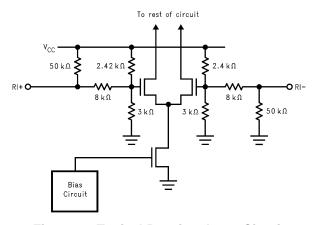


Figure 8. Typical Receiver Input Circuit

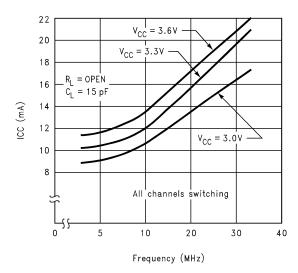


Figure 9. Typical I_{CC} vs Frequency

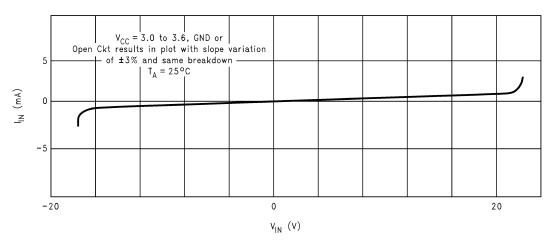


Figure 10. Receiver I_{IN} vs V_{IN} (Power On or Power Off)



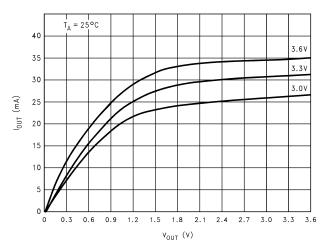


Figure 11. I_{OL} vs V_{OL}

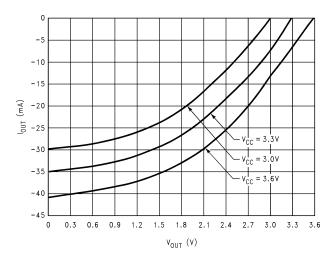


Figure 12. I_{OH} vs V_{OH}

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REVISION HISTORY

Changes from Revision B (February 2013) to Revision C							
•	Changed layout of National Data Sheet to TI format	9					





9-Mar-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
DS26LV32ATM	ACTIVE	SOIC	D	16	48	TBD	Call TI	Call TI	-40 to 85	DS26LV32A TM	Samples
DS26LV32ATM/NOPB	ACTIVE	SOIC	D	16	48	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	DS26LV32A TM	Samples
DS26LV32ATMX	ACTIVE	SOIC	D	16	2500	TBD	Call TI	Call TI	-40 to 85	DS26LV32A TM	Samples
DS26LV32ATMX/NOPB	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU SN	Level-1-260C-UNLIM	-40 to 85	DS26LV32A TM	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.

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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DS26LV32ATMX	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1
DS26LV32ATMX/NOPB	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.3	8.0	16.0	Q1

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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
DS26LV32ATMX	SOIC	D	16	2500	367.0	367.0	35.0
DS26LV32ATMX/NOPB	SOIC	D	16	2500	367.0	367.0	35.0

D (R-PDS0-G16)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



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